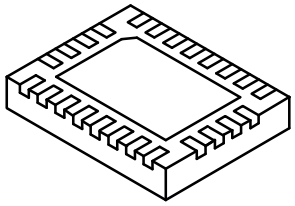
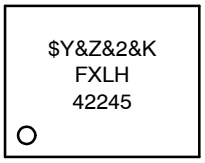
Low-Voltage, Dual-Supply, 8-Bit, Signal Translator with Configurable Voltage Supplies, Bushold Data Inputs, 3-State Outputs and 26 Ω Series Resistors in the B-Port Outputs

FXLH42245



WQFN24, 4.5 x 3.5, 0.5P
CASE 510CE

MARKING DIAGRAM



$Y	= **onsemi** logo
&Z	= Assembly Plant Code
&2	= 2−Digit Date Code
&K	= 2−Digits Lot Run Traceability Code
FXLH42245	= Specific Device Code

ORDERING INFORMATION

Device	Package	Shipping†
FXLH42245MPX	WQFN24 (Pb−Free)	3000 / Tape & Reel

†For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specification Brochure, BRD8011/D.

Description

The FXLH42245 is a configurable dual−voltage−supply translator designed for bi−directional voltage translation of signals between two voltage levels. The device allows translation between voltages as high as 3.6 V to as low as 1.1 V. The A port tracks the V_{CCA} level and the B port tracks the V_{CCB} level. Both ports are designed to accept supply voltage levels from 1.1 V to 3.6 V. This allows for bi−directional voltage translation over a variety of voltage levels: 1.2 V, 1.5 V, 1.8 V, 2.5 V, and 3.3 V.

The device remains in 3−state until both V_{CC}s reach active levels, allowing either V_{CC} to be powered−up first. The device also contains power−down control circuits that place the device in 3−state if either V_{CC} is removed.

The Transmit/Receive ($T/\overline{R}$) input determines the direction of data flow through the device. The $\overline{OE}$ input, when HIGH, disables both the A and B ports by placing them in a 3−state condition. The FXLH42245 is designed with the control pins ($T/\overline{R}$ and $\overline{OE}$) supplied by V_{CCA}.

Features

- Bi−Directional Interface between Two Levels from 1.1 V to 3.6 V
- Fully Configurable, Inputs Track V_{CC} Level
- Non−Preferential Power−Up; Either V_{CC} May Be Powered−Up First
- Outputs Remain in 3−State Until Active V_{CC} Level is Reached
- Outputs Switch to 3−State if Either V_{CC} is at GND
- Bushold on Data Inputs Eliminates the need for External Pull−Up / Pull−Down Resistors
- 26 Ω Output Series Resistors on the B Port to Reduce Line Noise
- Power−Off Protection
- Control Input ($T/\overline{R}$, $\overline{OE}$) Levels are Referenced to V_{CCA} Voltage
- Packaged in 24−Pin MLP
- ESD Protection Exceeds:
  - 4 kV Human Body Model (JESD22−A114 & Mil Std 883e 3015.7)
  - 8 kV Human Body Model I/O to GND (JESD22−A114 & Mil Std 883e 3015.7)
  - 1 kV Charge Device Model (ESD STM 5.3)
  - 200 V Machine Model (JESD22−A115 & ESD STM5.2)

© Semiconductor Components Industries, LLC, 2004

PIN CONFIGURATION

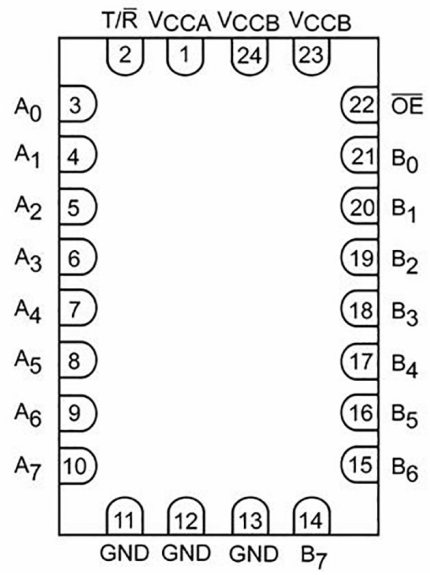


Figure 1. Pin Configuration (Top Through View)

PIN DEFINITIONS

Pin No.	Name	Description
1	V_{CCA}	Side−A Power Supply
2	$T/\overline{R}$	Transmit / Receive Input
3, 4, 5, 6, 7, 8, 9, 10	A_0, A_1, A_2, A_3, A_4, A_5, A_6, A_7	Side−A Inputs or 3−State Outputs
11, 12, 13	GND	Ground
14, 15, 16, 17, 18, 19, 20, 21	B_7, B_6, B_5, B_4, B_3, B_2, B_1, B_0	Side−B Inputs or 3−State Outputs
22	$\overline{OE}$	Output Enable Input
23, 24	V_{CCB}	Side−B Power Supply

TRUTH TABLE

Inputs		
$\overline{OE}$	$T/\overline{R}$	Description
LOW Voltage Level	LOW Voltage Level	Bus B Data to Bus A
LOW Voltage Level	HIGH Voltage Level	Bus A Date to Bus B
HIGH Voltage Level	Don't Care	3−State

ABSOLUTE MAXIMUM RATINGS

Symbol	Parameter	Condition		Min	Max	Unit
V_{CCA}	Supply Voltage			−0.5	4.6	V
V_{CCB}				−0.5	4.6	
V_I	DC Input Voltage	I/O Port A		−0.5	V_{CCA} + 0.5	V
		I/O Port B		−0.5	V_{CCB} + 0.5	
		Control Inputs (T/$\overline{R}$, $\overline{OE}$)		−0.5	4.6	
V_O	Output Voltage (Note 1)	Output 3−State		−0.5	4.6	V
		Output Active (A_n)		−0.5	V_{CCA} + 0.5	
		Output Active (B_n)		−0.5	V_{CCB} + 0.5	
I_{IK}	DC Input Diode Current	V_I < 0 V			−50	mA
I_{OK}	DC Output Diode Current	V_O < 0 V			−50	mA
		V_O > V_{CC}			50	
I_{OH}/I_{OL}	DC Output Source/Sink Current				±50	mA
I_{CC}	DC V_{CC} or Ground Current per Supply Pin				±100	mA
T_{STG}	Storage Temperature Range			−65	+150	°C
ESD	Electrostatic Discharge Capability	Human Body Model, JESD22−A114, Mil Std 883e 3015.7			4	kV
			I/O to GND		8	
		Charged Device Model, JESD22−C101, STM 5.3			1	
		Machine Model, JESD22−A115, STM 5.2			200	V

Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.
1. I/O absolute maximum ratings must be observed.

RECOMMENDED OPERATING CONDITIONS

Symbol	Parameter	Conditions		Min	Max	Unit
V_{CC}	Power Supply	Operating V_{CCA} or V_{CCB}		1.1	3.6	V
V_I	Input Voltage	Port A		0	V_{CCA}	V
		Port B		0	V_{CCB}	
		Control Input (T/$\overline{R}$, $\overline{OE}$)		0	V_{CCA}	
I_{OH}/I_{OL}	Output Current	Port A V_{CCA}	3.0 V to 3.6 V		±24	mA
			2.3 V to 2.7 V		±18	
			1.65 V to 1.95 V		±6	
			1.40 V to 1.65 V		±2	
			1.1 V to 1.4. V		±0.5	
		Port B V_{CCB} Resistor Outputs	3.0 V to 3.6 V		±14	
			2.3 V to 2.7 V		±8	
			1.65 V to 1.95 V		±3	
			1.40 V to 1.65 V		±1	
			1.1 V to 1.4. V		±0.25	
T_A	Operating Temperature, Free Air			−40	+85	°C
$\Delta V/\Delta t$	Input Edge Rate	$V_{CCA/B}$ = 1.1 V to 3.6 V			10	ns/V

Functional operation above the stresses listed in the Recommended Operating Ranges is not implied. Extended exposure to stresses beyond the Recommended Operating Ranges limits may affect device reliability.
2. All unused inputs must be held at V_{CCI} or GND.

ELECTRICAL CHARACTERISTICS

Symbol	Parameter	Conditions	V_{CCI} (V)	V_{CCO} (V)	Min	Max	Unit
V_{IH}	HIGH Level Input (Note 3)	Data Inputs An, Bn	2.70 to 3.60	1.1 to 3.6	2.0	–	V
			2.30 to 2.70		1.6	–	
			1.65 to 2.30		0.65 x V_{CCI}	–	
			1.40 to 1.65		0.65 x V_{CCI}	–	
			1.10 to 1.40		0.9 x V_{CCI}	–	
		Control Pins $\overline{OE}$, T/$\overline{R}$ (Referenced to V_{CCA})	2.70 to 3.60	1.1 to 3.6	2.0	–	
			2.30 to 2.70		1.6	–	
			1.65 to 2.30		0.65 x V_{CCA}	–	
			1.40 to 1.65		0.65 x V_{CCA}	–	
			1.10 to 1.40		0.9 x V_{CCA}	–	
V_{IL}	LOW Level Input (Note 3)	Data Inputs An, Bn	2.70 to 3.60	1.1 to 3.6	–	0.8	V
			2.30 to 2.70		–	0.7	
			1.65 to 2.30		–	0.35 x V_{CCI}	
			1.40 to 1.65		–	0.35 x V_{CCI}	
			1.10 to 1.40		–	0.10 x V_{CCI}	
		Control Pins $\overline{OE}$, T/$\overline{R}$ (Referenced to V_{CCA})	2.70 to 3.60	1.1 to 3.6	–	0.8	
			2.30 to 2.70		–	0.7	
			1.65 to 2.30		–	0.35 x V_{CCA}	
			1.40 to 1.65		–	0.35 x V_{CCA}	
			1.10 to 1.40		–	0.10 x V_{CCA}	
V_{OH}	HIGH Level Output B Port (Note 4)	I_{OH} = −100 μA	1.1 to 3.6	1.1 to 3.6	V_{CC0} to 0.2	–	V
		I_{OH} = −6 mA	2.7	2.7	2.2	–	
		I_{OH} = −8 mA	3.0	3.0	2.4	–	
		I_{OH} = −12 mA	3.0	3.0	2.2	–	
		I_{OH} = −4 mA	2.3	2.3	2.0	–	
		I_{OH} = −6 mA	2.3	2.3	1.8	–	
		I_{OH} = −8 mA	2.3	2.3	1.7	–	
		I_{OH} = −3 mA	1.65	1.65	1.25	–	
		I_{OH} = −1 mA	1.4	1.4	1.05	–	
		I_{OH} = −0.25 mA	1.1	1.1	0.75 x V_{CC0}	–	
	HIGH Level Output A Port (Note 4)	I_{OH} = −100 μA	1.1 to 3.6	1.1 to 3.6	V_{CC0} to 0.2	–	
		I_{OH} = −12 mA	2.7	2.7	2.2	–	
		I_{OH} = −18 mA	3.0	3.0	2.4	–	
		I_{OH} = −24 mA	3.0	3.0	2.2	–	
		I_{OH} = −6 mA	2.3	2.3	2.0	–	
		I_{OH} = −12 mA	2.3	2.3	1.8	–	
		I_{OH} = −18 mA	2.3	2.3	1.7	–	
		I_{OH} = −6 mA	1.65	1.65	1.25	–	
		I_{OH} = −2 mA	1.4	1.4	1.05	–	
		I_{OH} = −0.5 mA	1.1	1.1	0.75 x V_{CC0}	–	

ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Conditions	V_{CCI} (V)	V_{CCO} (V)	Min	Max	Unit
V_{OL}	LOW Level Output B Port (Note 4)	I_{OH} = 100 μA	1.1 to 3.6	1.1 to 3.6	–	0.2	V
		I_{OH} = 6 mA	2.7	2.7	–	0.4	
		I_{OH} = 8 mA	3.0	3.0	–	0.55	
		I_{OH} = 12 mA	3.0	3.0	–	0.80	
		I_{OH} = 6 mA	2.3	2.3	–	0.4	
		I_{OH} = 8 mA	2.3	2.3	–	0.6	
		I_{OH} = 3 mA	1.65	1.65	–	0.3	
		I_{OH} = 1 mA	1.4	1.4	–	0.35	
		I_{OH} = 0.25 mA	1.1	1.1	–	0.3 x V_{CC0}	
	LOW Level Output A Port (Note 4)	I_{OH} = 100 μA	1.1 to 3.6	1.1 to 3.6	–	0.2	
		I_{OH} = 12 mA	2.7	2.7	–	0.4	
		I_{OH} = 18 mA	3.0	3.0	–	0.4	
		I_{OH} = 24 mA	3.0	3.0	–	0.55	
		I_{OH} = 12 mA	2.3	2.3	–	0.4	
		I_{OH} = 18 mA	2.3	2.3	–	0.6	
		I_{OH} = 6 mA	1.65	1.65	–	0.3	
		I_{OH} = 2 mA	1.4	1.4	–	0.35	
		I_{OH} = 0.5 mA	1.1	1.1	–	0.3 x V_{CC0}	
I_L	Input Leakage Current, Control Pins	V_I = V_{CCA} or GND	1.1 to 3.6	3.6	–	±1.0	μA
$I_{I(HOLD)}$	Bushold Input Minimum Drive Current	V_{IN} = 0.8	3.0	3.0	75	–	μA
		V_{IN} = 2.0	3.0	3.0	−75	–	
		V_{IN} = 0.7	2.3	2.3	45	–	
		V_{IN} = 1.6	2.3	2.3	−45	–	
		V_{IN} = 0.57	1.65	1.65	25	–	
		V_{IN} = 10.7	1.65	1.65	−25	–	
		V_{IN} = 0.49	1.4	1.4	11	–	
		V_{IN} = 0.91	1.4	1.4	−11	–	
		V_{IN} = 0.11	1.1	1.1	–	4	
		V_{IN} = 0.99	1.1	1.1	–	−4	
$I_{I(OD)}$	Bushold Input Over−Drive Current−to−Current State	(Note 5)	3.6	3.6	450	–	μA
		(Note 6)	3.6	3.6	−450	–	
		(Note 5)	2.7	2.7	300	–	
		(Note 6)	2.7	2.7	−300	–	
		(Note 5)	1.95	1.95	200	–	
		(Note 6)	1.95	1.95	−200	–	
		(Note 5)	1.6	1.6	120	–	
		(Note 6)	1.6	1.6	−120	–	
		(Note 5)	1.4	1.4	80	–	
		(Note 6)	1.4	1.4	−80	–	

ELECTRICAL CHARACTERISTICS (continued)

Symbol	Parameter	Conditions	V_{CCI} (V)	V_{CCO} (V)	Min	Max	Unit
I_{OFF}	Power Off Leakage Current	A_n, V_I or V_O = 0 V to 3.6 V	0	3.6	–	±10	μA
		B_n, V_I or V_O = 0 V to 3.6 V	3.6	0	–	±10	
I_{OZ}	3−State Output Leakage (V_O, V_{CC} or GND V_I = V_{IH} or V_{IL})	A_n, B_n, $\overline{OE}$ = V_{IH}	3.6	3.6	–	±10	μA
		Bn, $\overline{OE}$ = Don't Care (Note 7)	0	3.6	–	±10	
		An, $\overline{OE}$ = Don't Care (Note 7)	3.6	0	–	±10	
$I_{CCA/B}$	Quiescent Supply Current (Note 8)	V_I = V_{CCI} or GND; I_O = 0	1.1 to 3.6	1.1 to 3.6	–	20	μA
I_{CCZ}			1.1 to 3.6	1.1 to 3.6	–	20	μA
I_{CCA}		V_I = V_{CCA} or GND; I_O = 0	0	1.1 to 3.6	–	−10	μA
			1.1 to 3.6	0	–	10	
I_{CCB}		V_I = V_{CCB} or GND; I_O = 0	1.1 to 3.6	0	–	−10	μA
			0	1.1 to 3.6	–	10	
$\Delta I_{CCA/B}$	Increase in I_{CC} per Input; Other Inputs at V_{CC} or GND	V_{IH} = 3.0	3.6	3.6	–	500	μA

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

3. V_{CCI} = the V_{CC} associated with the data input under test.
4. V_{CCO} = the VCC associated with the output under test.
5. An external driver must source at least the specified current to switch LOW−to−HIGH.
6. An external driver must source at least the specified current to switch HIGH−to−LOW.
7. Don't care = any valid logic level.
8. Reflects current per supply, V_{CCA} or V_{CCB}.

AC ELECTRICAL CHARACTERISTICS

V_{CCA} = 3.0 V to 3.6 V

		T_A = −40°C to +85°C										
		V_{CCB} = 3.0 V to 3.6 V		V_{CCB} = 2.3 V to 2.7 V		V_{CCB} = 1.65 V to 1.95 V		V_{CCB} = 1.4 V to 1.6 V		V_{CCB} = 1.1 V to 1.3 V		
Symbol	Parameter	Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	Unit
t_{PLH}, t_{PHL}	Propagation Delay A to B	0.5	3.9	0.5	4.5	0.9	5.9	1.0	7.4	1.6	22.0	ns
	Propagation Delay B to A	0.2	3.5	0.2	3.8	0.3	4.0	0.5	4.3	0.8	13.0	
t_{PZL}, t_{PZH}	Output Enable $\overline{OE}$−to−B	0.7	4.8	1.0	5.1	1.5	6.7	1.5	7.1	2.0	18.0	ns
	Output Enable $\overline{OE}$−to−A	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	0.5	4.0	
t_{PHZ}, t_{PZL}	Output Enable $\overline{OE}$−to−B	0.4	4.3	0.4	4.4	0.9	5.2	1.7	6.8	2.0	19.0	ns
	Output Enable $\overline{OE}$−to−A	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	0.2	3.7	

AC ELECTRICAL CHARACTERISTICS (continued)

V_{CCA} = 2.3 V to 2.7 V

Symbol	Parameter	T_A = −40°C to +85°C										Unit
		V_{CCB} = 3.0 V to 3.6 V		V_{CCB} = 2.3 V to 2.7 V		V_{CCB} = 1.65 V to 1.95 V		V_{CCB} = 1.4 V to 1.6 V		V_{CCB} = 1.1 V to 1.3 V		
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay A to B	0.5	4.3	0.6	4.8	0.9	6.0	1.0	7.6	1.6	22.0	ns
	Propagation Delay B to A	0.3	3.9	0.4	4.2	0.5	4.5	0.5	4.8	1.0	7.0	
t_{PZL}, t_{PZH}	Output Enable $\overline{OE}$–to–B	0.8	5.1	1.0	5.5	1.5	6.9	1.5	7.4	2.0	19.0	ns
	Output Enable $\overline{OE}$–to–A	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	0.6	4.5	
t_{PHZ}, t_{PZL}	Output Enable $\overline{OE}$–to–B	0.4	4.6	0.4	4.8	0.9	5.3	1.7	7.1	2.0	19.0	ns
	Output Enable $\overline{OE}$–to–A	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	0.2	4.0	

V_{CCA} = 1.65 V to 1.95 V

Symbol	Parameter	T_A = −40°C to +85°C										Unit
		V_{CCB} = 3.0 V to 3.6 V		V_{CCB} = 2.3 V to 2.7 V		V_{CCB} = 1.65 V to 1.95 V		V_{CCB} = 1.4 V to 1.6 V		V_{CCB} = 1.1 V to 1.3 V		
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay A to B	0.5	4.6	0.7	5.1	1.1	6.2	1.1	7.8	1.7	22.0	ns
	Propagation Delay B to A	0.5	5.4	0.5	5.6	0.8	5.7	1.0	6.0	1.2	8.0	
t_{PZL}, t_{PZH}	Output Enable $\overline{OE}$–to–B	0.8	5.4	1.0	5.9	1.5	7.3	1.5	7.7	2.0	20.0	ns
	Output Enable $\overline{OE}$–to–A	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	1.0	6.7	
t_{PHZ}, t_{PZL}	Output Enable $\overline{OE}$–to–B	0.4	4.7	0.4	4.9	1.0	5.4	1.7	7.2	2.0	19.0	ns
	Output Enable $\overline{OE}$–to–A	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	0.5	5.0	

AC ELECTRICAL CHARACTERISTICS (continued)

V_{CCA} = 1.4 V to 1.6 V

Symbol	Parameter	T_A = −40°C to +85°C										Unit
		V_{CCB} = 3.0 V to 3.6 V		V_{CCB} = 2.3 V to 2.7 V		V_{CCB} = 1.65 V to 1.95 V		V_{CCB} = 1.4 V to 1.6 V		V_{CCB} = 1.1 V to 1.3 V		
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay A to B	0.7	4.8	0.8	5.3	1.2	6.4	1.3	7.9	1.7	22.0	ns
	Propagation Delay B to A	0.6	6.8	0.8	6.9	0.9	7.1	1.0	7.3	1.2	9.5	
t_{PZL}, t_{PZH}	Output Enable $\overline{OE}$–to–B	1.1	5.8	1.3	6.3	1.5	7.8	2.0	8.1	2.0	20.0	ns
	Output Enable $\overline{OE}$–to–A	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	1.0	7.5	
t_{PHZ}, t_{PZL}	Output Enable $\overline{OE}$–to–B	0.6	4.8	0.6	5.1	1.1	5.8	2.0	7.7	2.0	18.0	ns
	Output Enable $\overline{OE}$–to–A	1.0	6.0	1.0	6.0	1.0	6.0	1.0	6.0	0.5	6.0	

V_{CCA} = 1.1 V to 1.3 V

Symbol	Parameter	T_A = −40°C to +85°C										Unit
		V_{CCB} = 3.0 V to 3.6 V		V_{CCB} = 2.3 V to 2.7 V		V_{CCB} = 1.65 V to 1.95 V		V_{CCB} = 1.4 V to 1.6 V		V_{CCB} = 1.1 V to 1.3 V		
		Min	Max	Min	Max	Min	Max	Min	Max	Min	Max	
t_{PLH}, t_{PHL}	Propagation Delay A to B	1.0	13.8	1.0	7.8	1.0	8.4	1.0	10.4	2.0	24.0	ns
	Propagation Delay B to A	1.4	22.0	1.4	22.0	1.5	22.0	1.5	22.0	2.0	24.0	
t_{PZL}, t_{PZH}	Output Enable $\overline{OE}$–to–B	1.5	12.6	1.5	9.6	1.5	10.6	2.0	11.6	2.0	24.0	ns
	Output Enable $\overline{OE}$–to–A	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	2.0	22.0	
t_{PHZ}, t_{PZL}	Output Enable $\overline{OE}$–to–B	1.2	15.0	0.9	7.6	1.2	8.6	2.0	10.6	3.0	21.0	ns
	Output Enable $\overline{OE}$–to–A	2.0	15.0	2.0	12.0	2.0	12.0	2.0	12.0	2.0	12.0	

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

CAPACITANCE

Symbol	Parameter	Conditions	Typical (T_A = 25°C)	Unit
C_{IN}	Input Capacitance Control Pins ($\overline{OE}$, T/$\overline{R}$)	V_{CCA} = V_{CCB} = 3.3 V, V_I = 0 V or $V_{CCA/B}$	4	pF
$C_{I/O}$	Input / Output Capacitance A_n, B_n Port	V_{CCA} = V_{CCB} = 3.3 V, V_I = 0 V or $V_{CCA/B}$	5	pF
C_{PD}	Power Dissipation Capacitance	V_{CCA} = V_{CCB} = 3.3 V, V_I = 0 V or V_{CC}, f = 10 MHz	20	pF

AC LOADINGS AND WAVEFORMS

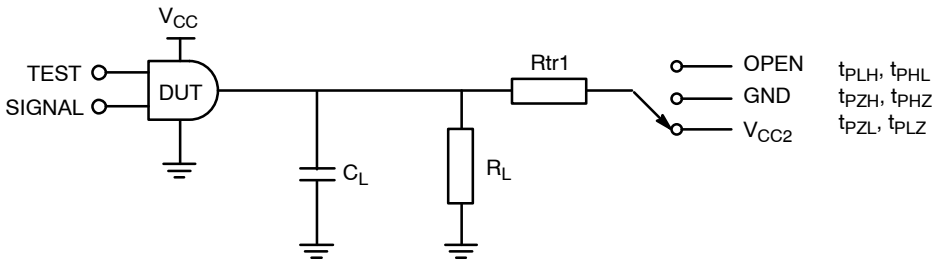


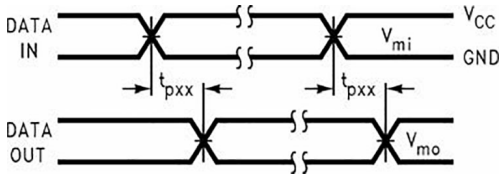
Figure 2. AC Test Circuit

Table 1. TEST CIRCUIT PARAMETERS

Test	Switch
t_{PLH}, t_{PHL}	Open
t_{PLZ}, t_{PZL}	V_{CC0} • 2 at V_{CC0} = 3.3 + 0.3 V, 2.5 V + 0.2 V, 1.8 V + 0.15 V, 1.5 V + 0.1 V, 1.2 V + 0.1 V
t_{PHZ}, t_{PZH}	GND

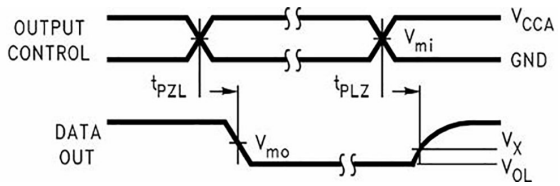
Table 2. AC LOAD TABLE

V_{CC0}	C_L	R_L	Rtr1
1.2 V ± 0.1 V	15 pF	2 kΩ	2 kΩ
1.5 V ± 0.1 V	15 pF	2 kΩ	2 kΩ
1.8 V ± 0.15 V	30 pF	500 Ω	500 Ω
2.5 V ± 0.2 V	30 pF	500 Ω	500 Ω
3.3 V ± 0.3 V	30 pF	500 Ω	500 Ω



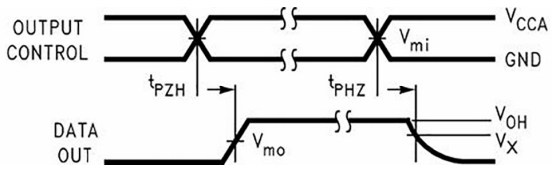
9. Input $t_R = t_F$ = 2.0 ns, 10% to 90%

Figure 3. Waveform for Inverting and Non–Inverting Functions



10. Input $t_R = t_F$ = 2.0 ns, 10% to 90%

Figure 4. 3–State Output High Enable and Disable for Low Voltage Logic



11. Input $t_R = t_F$ = 2.0 ns, 10% to 90%

Figure 5. 3–State Output High Enable and Disable for Low Voltage Logic

Table 3.

Symbol	V_{CC}				
	3.3 V ± 0.3 V	**2.5 V ± 0.2 V**	**1.8 V ± 0.15 V**	**1.5 V ± 0.1 V**	**1.2 V ± 0.1 V**
V_{MI}	$V_{CCI}/2$	$V_{CCI}/2$	$V_{CCI}/2$	$V_{CCI}/2$	$V_{CCI}/2$
V_{MO}	$V_{CCO}/2$	$V_{CCO}/2$	$V_{CCO}/2$	$V_{CCO}/2$	$V_{CCO}/2$
V_X	V_{OH} − 0.3 V	V_{OH} − 0.15 V	V_{OH} − 0.15 V	V_{OH} − 0.1 V	V_{OH} − 0.1 V
V_Y	V_{OL} + 0.3 V	V_{OL} + 0.15 V	V_{OL} + 0.15 V	V_{OL} + 0.1 V	V_{OL} + 0.1 V

12. For V_{MI} V_{CCO} = V_{CCA} for control pins T/$\overline{R}$ and $\overline{OE}$ or $V_{CCA}/2$.

FUNCTIONAL DESCRIPTION

Power−Up/Power−Down Sequencing

FXL translators offer an advantage in that either VCC may be powered up first. This benefit derives from the chip design. When either V_{CC} is at 0 V, outputs are in a High−impedance state. The control inputs (T/$\overline{R}$ and $\overline{OE}$) are designed to track the V_{CCA} supply. A pull−up resistor tying $\overline{OE}$ to V_{CCA} should be used to ensure that bus contention, excessive currents, or oscillations do not occur during power−up/power−down. The size of the pull−up resistor is based upon the current−sinking capability of the OE driver.

The recommended power−up sequence is:

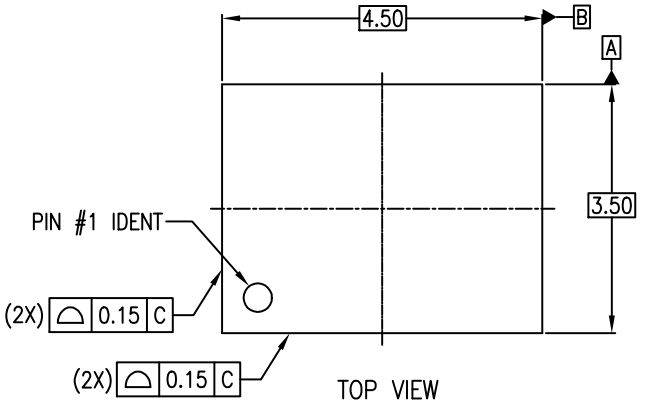
1. Apply power to either V_{CC}.
2. Apply power to the T/$\overline{R}$ input (logic HIGH for A−to−B operation; logic LOW for B−to−A operation) and to the respective data inputs (A port or B port). This may occur at the same time as step 1.
3. Apply power to the other V_{CC}.
4. Drive the $\overline{OE}$ input LOW to enable the device.

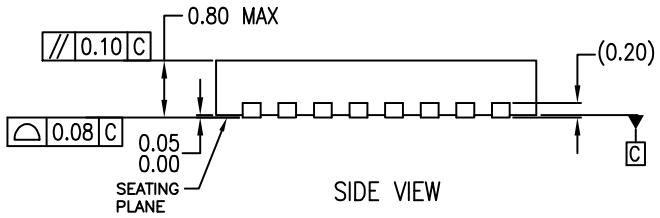
The recommended power−down sequence is:

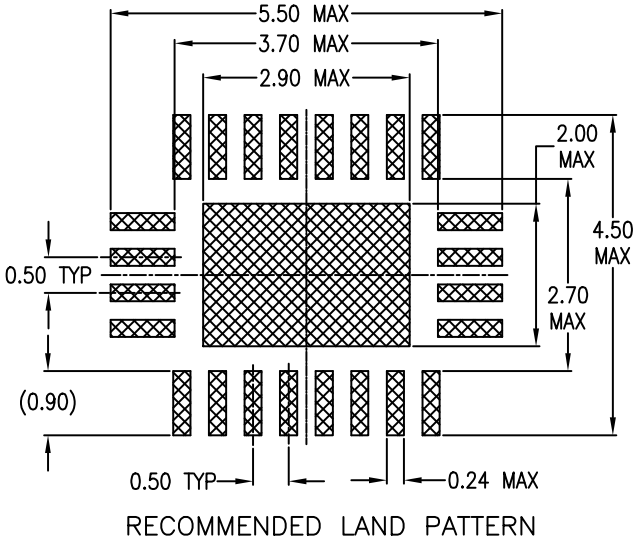
1. Drive $\overline{OE}$ input HIGH to disable the device.
2. Remove power from either V_{CC}.
3. Remove power from the other V_{CC}.

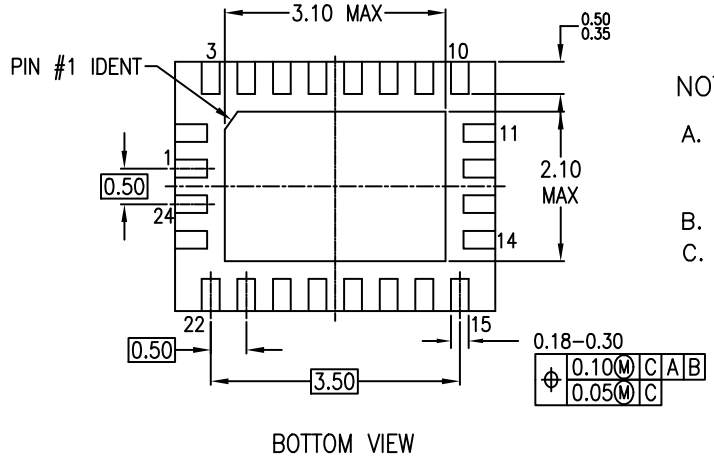
WQFN24 4.5x3.5, 0.5P
CASE 510CE
ISSUE O

DATE 31 AUG 2016









NOTES:

A. CONFORMS TO JEDEC REGISTRATION MO–220, VARIATION WFSD–2 FOR DIMENSIONS ONLY. PIN NUMBERING DOES NOT COMPLY.
B. DIMENSIONS ARE IN MILLIMETERS.
C. DIMENSIONS AND TOLERANCES PER ASME Y14.5M, 1994

DOCUMENT NUMBER:	**98AON13646G**	Electronic versions are uncontrolled except when accessed directly from the Document Repository. Printed versions are uncontrolled except when stamped "CONTROLLED COPY" in red.
DESCRIPTION:	**WQFN24 4.5X3.5, 0.5P**	**PAGE 1 OF 1**

ON Semiconductor and ON are trademarks of Semiconductor Components Industries, LLC dba ON Semiconductor or its subsidiaries in the United States and/or other countries. ON Semiconductor reserves the right to make changes without further notice to any products herein. ON Semiconductor makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does ON Semiconductor assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. ON Semiconductor does not convey any license under its patent rights nor the rights of others.

© Semiconductor Components Industries, LLC, 2019

onsemi, , and other names, marks, and brands are registered and/or common law trademarks of Semiconductor Components Industries, LLC dba "**onsemi**" or its affiliates and/or subsidiaries in the United States and/or other countries. **onsemi** owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of **onsemi**'s product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent−Marking.pdf. **onsemi** reserves the right to make changes at any time to any products or information herein, without notice. The information herein is provided "as−is" and **onsemi** makes no warranty, representation or guarantee regarding the accuracy of the information, product features, availability, functionality, or suitability of its products for any particular purpose, nor does **onsemi** assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. Buyer is responsible for its products and applications using **onsemi** products, including compliance with all laws, regulations and safety requirements or standards, regardless of any support or applications information provided by **onsemi**. "Typical" parameters which may be provided in **onsemi** data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. **onsemi** does not convey any license under any of its intellectual property rights nor the rights of others. **onsemi** products are not designed, intended, or authorized for use as a critical component in life support systems or any FDA Class 3 medical devices or medical devices with a same or similar classification in a foreign jurisdiction or any devices intended for implantation in the human body. Should Buyer purchase or use **onsemi** products for any such unintended or unauthorized application, Buyer shall indemnify and hold **onsemi** and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that **onsemi** was negligent regarding the design or manufacture of the part. **onsemi** is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.

ADDITIONAL INFORMATION

TECHNICAL PUBLICATIONS:
Technical Library: www.onsemi.com/design/resources/technical−documentation
onsemi Website: www.onsemi.com

ONLINE SUPPORT: www.onsemi.com/support
For additional information, please contact your local Sales Representative at www.onsemi.com/support/sales

Unikeyic Electronics

Global Electronic Components Distributor

Click to view pricing, inventory, delivery, and lifecycle information:

Fairchild Semiconductor:

1N4148 DM7407MX 74ACQ573SCX 74VCX245MTCX H11L1M MM74HC132M FDP12N60NZ FSL126MR ISL9V3040P3 KA278R12CYDTU MM74HC139N 1N4148TA 74VHC573MX FQPF3N80C HLMP0504